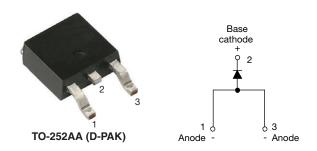


High Voltage Surface Mount Input Rectifier Diode, 8 A



PRODUCT SUMMARY					
Package	TO-252AA (D-PAK)				
I _{F(AV)}	8 A				
V_{R}	1600 V				
V _F at I _F	1.1 V				
I _{FSM}	150 A				
T _J max.	150 °C				
Diode variation	Single die				

FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C







ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

- · Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-8EWS16S-M3 rectifier high voltage series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

The **high reverse voltage** range available allows design of input stage primary rectification with **outstanding voltage surge** capability.

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS						
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 μm) copper	1.2	1.6				
Aluminum IMS, R _{thCA} = 15 °C/W	2.5	2.8	A			
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	5.5	6.5				

Note

T_A = 55 °C, T_J = 125 °C, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	MBOL CHARACTERISTICS VALUES UNITS							
I _{F(AV)}	Sinusoidal waveform	8	Α					
V _{RRM}		1600	V					
I _{FSM}		150	Α					
V _F	8 A, T _J = 25 °C	1.10	V					
TJ		-40 to +150	°C					

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-8EWS16S-M3	1600	1700	0.5				



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS				
Maximum average forward current	I _{F(AV)}	$T_C = 105$ °C, 180 ° conduction half sine wave	8		
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated V _{RRM} applied	125	А	
	I _{FSM}	10 ms sine pulse, no voltage reapplied	150		
Maximum I ² t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	78	- A ² s	
Maximum I-t for fusing	I-I	10 ms sine pulse, no voltage reapplied	110	A-S	
Maximum I²√t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	1100	A²√s	

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS VALUES UNITS				
Maximum forward voltage drop	V_{FM}	8 A, T _J = 25 °C		1.1	V	
Forward slope resistance	r _t	T 450 °C		20	mΩ	
Threshold voltage	V _{F(TO)}	T _J = 150 °C		0.82	V	
Maximum reverse leakage current	l	T _J = 25 °C V _B = Rated V _{BBM}		0.05	mA	
Maximum reverse leakage current	IRM	T _J = 150 °C	VR = nateu VRRM	0.50	IIIA	

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C	
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	2.5	°C/W	
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		62	C/VV	
Approximate weight			1	g	
Approximate weight			0.03	oz.	
Marking device		Case style TO-252AA (D-PAK)	8EW	S16S	

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

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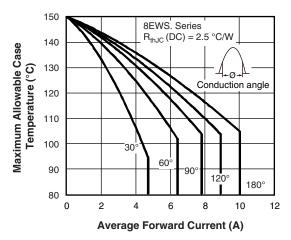


Fig. 1 - Current Rating Characteristics

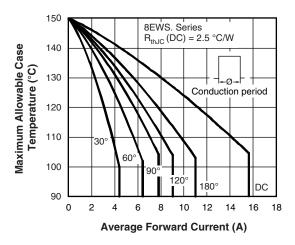


Fig. 2 - Current Rating Characteristics

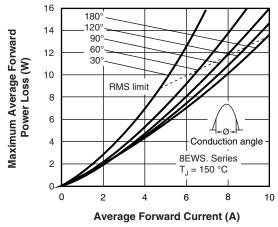


Fig. 3 - Forward Power Loss Characteristics

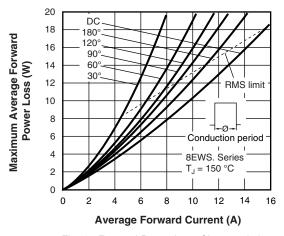


Fig. 4 - Forward Power Loss Characteristics

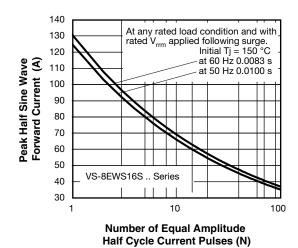


Fig. 5 - Maximum Non-Repetitive Surge Current

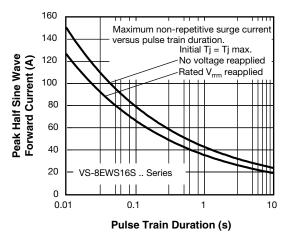


Fig. 6 - Maximum Non-Repetitive Surge Current

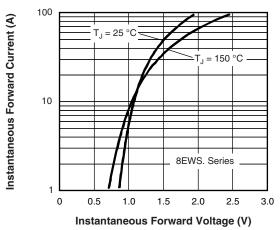


Fig. 7 - Forward Voltage Drop Characteristics

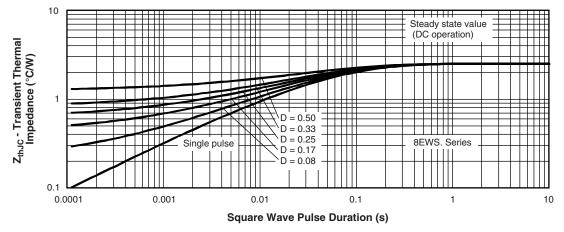
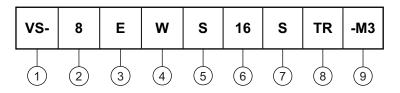


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE





- 1 Vishay Semiconductors product
- Current rating (8 = 8 A)
- 3 Circuit configuration:

E = single diode

4 - Package:

W = D-PAK

5 - Type of silicon:

S = standard recovery rectifier

- 6 Voltage code x 100 = V_{RRM} (16 = 1600 V)
- 7 S = surface mountable
- 8 • TR = tape and reel
 - TRR = tape and reel (right oriented)
 - TRL = tape and reel (left oriented)
- 9 Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

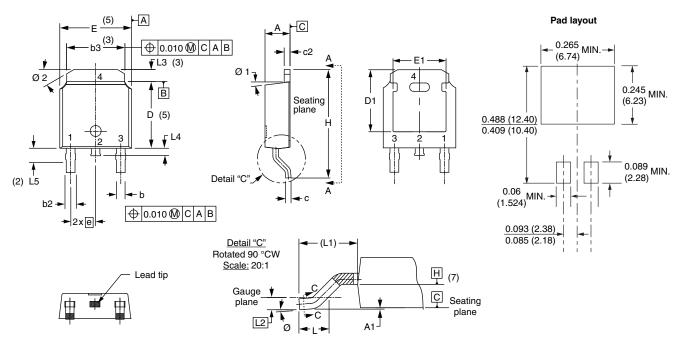
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-8EWS16S-M3	75	3000	Antistatic plastic tubes			
VS-8EWS16STR-M3	2000	2000	13" diameter reel			
VS-8EWS16STRL-M3	3000	3000	13" diameter reel			
VS-8EWS16STRR-M3	3000	3000	13" diameter reel			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95627			
Part marking information	www.vishay.com/doc?95176			
Packaging information	www.vishay.com/doc?95033			



D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	2.18	2.39	0.086	0.094		
A1	-	0.13	-	0.005		
b	0.64	0.89	0.025	0.035		
b2	0.76	1.14	0.030	0.045		
b3	4.95	5.46	0.195	0.215	3	
С	0.46	0.61	0.018	0.024		
c2	0.46	0.89	0.018	0.035		
D	5.97	6.22	0.235	0.245	5	
D1	5.21	-	0.205	-	3	
Е	6.35	6.73	0.250	0.265	5	
E1	4.32	-	0.170	-	3	

SYMBOL		SYMBOL	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
е	2.29	BSC	0.090	BSC		
Н	9.40	10.41	0.370	0.410		
L	1.40	1.78	0.055	0.070		
L1	2.74 BSC		0.108	REF.		
L2	0.51 BSC		0.020 BSC			
L3	0.89	1.27	0.035	0.050	3	
L4	-	1.02	-	0.040		
L5	1.14	1.52	0.045	0.060	2	
Ø	0°	10°	0°	10°		
Ø1	0°	15°	0°	15°		
Ø2	25°	35°	25°	35°		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA



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